

Date: 26 Nov. 2012

To Whom It May Concern:

RoHS Certificate of Compliance

We certify that our microwave semiconductor products indicated below are in compliance with EU Directive 2011/65/EU on the Restriction of Hazardous Substances (RoHS).

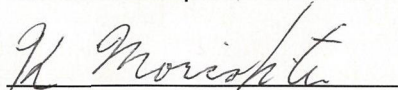
1. Applicable Product Type

Toshiba Product Type	Description
TGI series	Internally Matched Power GaN HEMTs
TIM series	Internally Matched Power GaAs FETs
TMD series	GaAs MMICs
TPM series	Partially Matched Power GaAs FETs
JS8 series	Medium Power GaAs FETs, Chip Form
S8 series	Medium Power GaAs FETs, Packaged Model

2. Substances and the maximum allowable concentration (Threshold level)

Substance	Threshold level	Contained level
1) Cadmium and its compound	< 100 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
2) Lead and its compound	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
3) Hexavalent chromium and its compound	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
4) Mercury and its compound	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
5) Polybrominated biphenyls (PBBs)	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below
6) Polybrominated diphenyl ethers (PBDEs)	< 1000 ppm	<input type="checkbox"/> Exceed <input checked="" type="checkbox"/> Below

Company: Komukai Complex, Social Infrastructure System Company, Toshiba Corporation

Signature: 

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